



NEC's 1/2W L, S-BAND SPDT SWITCH

UPG168TB

FEATURES

- **SWITCH CONTROL VOLTAGE:**
 $V_{cont(H)} = 2.5$ to 5.3 V (3.0 V TYP.)
 $V_{cont(L)} = -0.2$ to $+0.2$ V (0 V TYP.)
- **LOW INSERTION LOSS:**
 $LINS1 = 0.30$ dB TYP. @ $f = 0.5$ to 1.0 GHz, $V_{cont} = 3.0$ V/0 V
 $LINS2 = 0.40$ dB TYP. @ $f = 2.0$ GHz, $V_{cont} = 3.0$ V/0 V
 $LINS3 = 0.90$ dB MAX. @ $f = 2.0$ to 2.5 GHz, $V_{cont} = 3.0$ V/0 V
- **HIGH ISOLATION:**
 $ISL1 = 27$ dB TYP. @ $f = 0.5$ to 2.0 GHz, $V_{cont} = 3.0$ V/0 V
 $ISL2 = 18$ dB MIN. @ $f = 2.0$ to 2.5 GHz, $V_{cont} = 3.0$ V/0 V
- **POWER HANDLING:**
 $P_{in(1\text{ dB})} = +26.5$ dBm TYP. @ $f = 1.0$ GHz, $V_{cont} = 3.0$ V/0 V
- **HIGH-DENSITY SURFACE MOUNTING:**
6-pin super minimold package ($2.0 \times 1.25 \times 0.9$ mm)

DESCRIPTION

NEC's UPG168TB is a GaAs MMIC L, S-band SPDT (Single Pole Double Throw) switch for mobile phone and L, S-band applications.

This device can operate from 0.5 to 2.5 GHz, with low insertion loss and high isolation.

This device is housed in a 6-pin super minimold package, suitable for high-density surface mount assembly.

APPLICATIONS

- L-band digital cellular or cordless telephones
- PCS, W-LAN, WLL and Bluetooth™
- Short Range Wireless

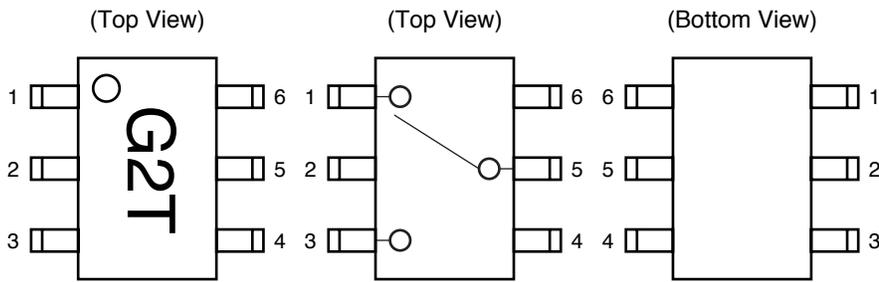
ORDERING INFORMATION

Part Number	Package	Marking	Supplying Form
UPG168TB-E4	6-pin super minimold	G2T	<ul style="list-style-type: none">• Embossed tape 8 mm wide• Pin 1, 2, 3 face the perforation side of the tape• Qty 3 kpcs/reel

Remark To order evaluation samples, contact your nearby sales office.
Part number for sample order: UPG168TB

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

PIN CONNECTION DIAGRAM



Pin No.	Pin Name
1	OUTPUT2
2	GND
3	OUTPUT1
4	V _{Cont1}
5	INPUT
6	V _{Cont2}

TRUTH TABLE

V _{cont1}	V _{cont2}	INPUT-OUTPUT1	INPUT-OUTPUT2
Low	High	ON	OFF
High	Low	OFF	ON

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Switch Control Voltage	V _{cont}	-6.0 to +6.0 ^{Note1}	V
Input Power	P _{in}	+28	dBm
Power Dissipation	P _D	150 ^{Note2}	mW
Operating Ambient Temperature	T _A	-45 to +85	°C
Storage Temperature	T _{stg}	-55 to +150	°C

- Note** 1. Mounted on double-sided copper-clad 50 × 50 × 1.6 mm epoxy glass PWB, T_A = +85°C
 2. | V_{cont1} - V_{cont2} | ≤ 6.0 V

RECOMMENDED OPERATING RANGE (T_A = 25°C, unless otherwise specified)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Switch Control Voltage (H)	V _{cont (H)}	2.5	3.0	5.3	V
Switch Control Voltage (L)	V _{cont (L)}	-0.2	0	0.2	V

ELECTRICAL CHARACTERISTICS

(T_A = +25°C, V_{cont} = 3.0 V/0 V, DC blocking capacitors = 51 pF, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Insertion Loss 1	L _{INS1}	f = 0.5 to 1.0 GHz	-	0.30	0.55	dB
Insertion Loss 2	L _{INS2}	f = 2.0 GHz	-	0.40	0.65	dB
Insertion Loss 3	L _{INS3}	f = 2.0 to 2.5 GHz	-	-	0.90	dB
Isolation 1	ISL1	f = 0.5 to 2.0 GHz	22	27	-	dB
Isolation 2	ISL2	f = 2.0 to 2.5 GHz	18	-	-	dB
Input Return Loss 1	RL _{in1}	f = 0.5 to 2.0 GHz	13	19	-	dB
Input Return Loss 2	RL _{in2}	f = 2.0 to 2.5 GHz	11	-	-	dB
Output Return Loss 1	RL _{out1}	f = 0.5 to 2.0 GHz	13	19	-	dB
Output Return Loss 2	RL _{out2}	f = 2.0 to 2.5 GHz	11	-	-	dB
1 dB Gain Compression Input Power Note	P _{in (1 dB)}	f = 1.0 GHz	+22.0	+26.5	-	dBm
Switch Control Speed	t _{sw}		-	50	200	ns
Switch Control Current	I _{cont}		-	0.5	10	μA

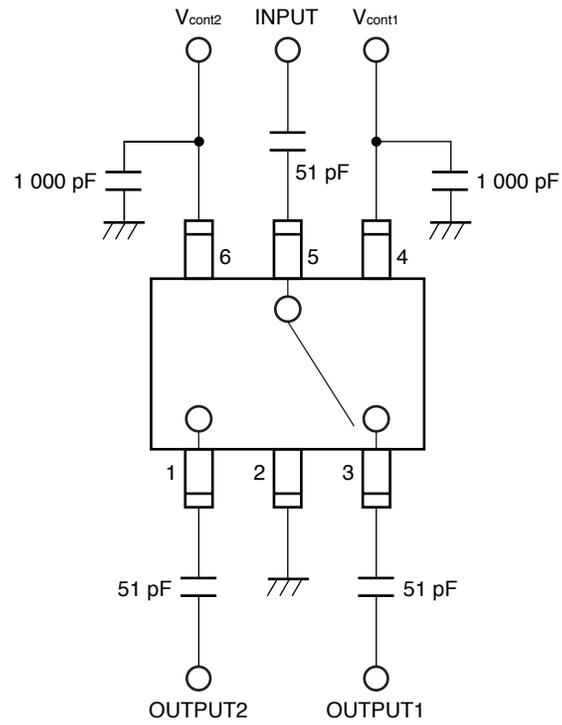
Note P_{in (1 dB)} is the measured input power level when the insertion loss increases 1 dB more than that of linear range.

STANDARD CHARACTERISTICS FOR REFERENCE

(T_A = +25°C, V_{cont} = 3.0 V/0 V, DC blocking capacitors = 51 pF, unless otherwise specified)

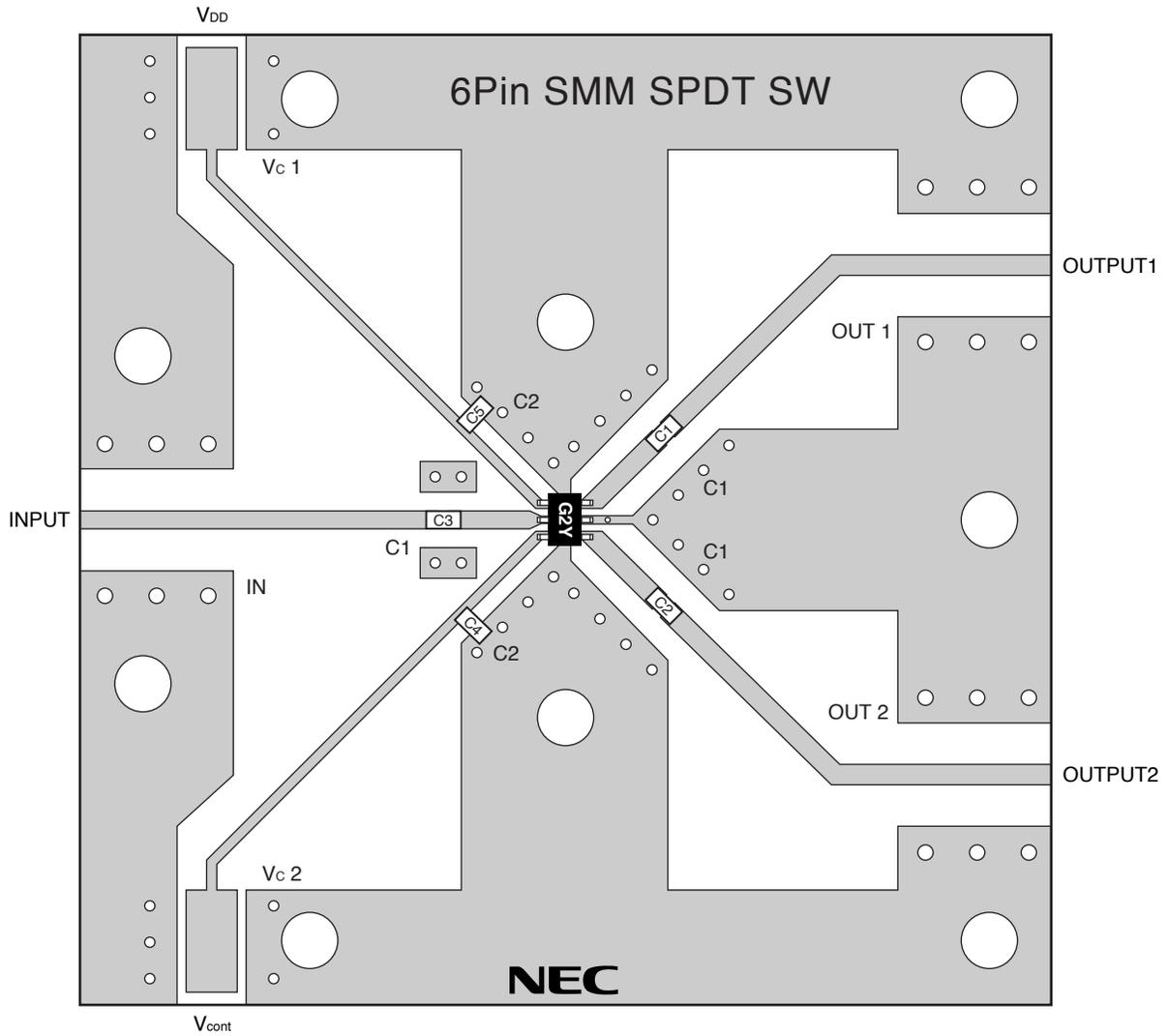
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
0.1 dB Gain Compression Input Power Note	P _{in (0.1 dB)}	f = 1.0 GHz	-	+23.0	-	dBm

Note P_{in (0.1 dB)} is the measured input power level when the insertion loss increases 0.1 dB more than that of linear range.

EVALUATION CIRCUIT ($V_{cont} = 3.0 \text{ V}/0 \text{ V}$, DC blocking capacitors = 51 pF)

The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD

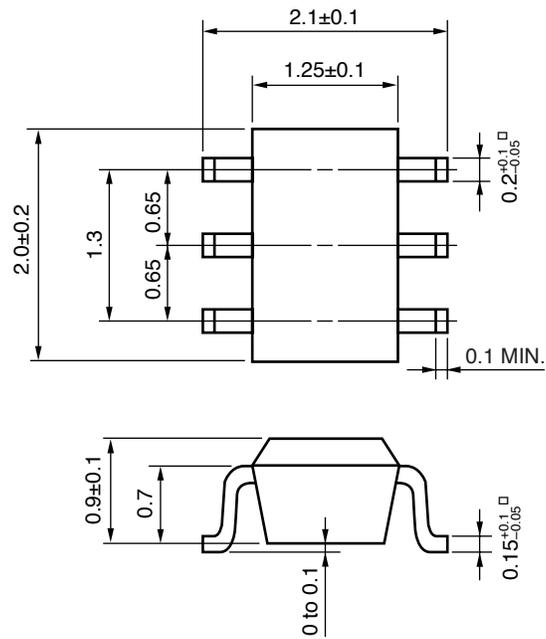


USING THE NEC EVALUATION BOARD

Symbol	Values
C1, C2, C3	51 pF
C4, C5	1 000 pF

PACKAGE DIMENSIONS

6-PIN SUPER MINIMOLD (UNIT: mm)



RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) : 260°C or below Time at peak temperature : 10 seconds or less Time at temperature of 220°C or higher : 60 seconds or less Preheating time at 120 to 180°C : 120±30 seconds Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	IR260
VPS	Peak temperature (package surface temperature) : 215°C or below Time at temperature of 200°C or higher : 25 to 40 seconds Preheating time at 120 to 150°C : 30 to 60 seconds Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	VP215
Wave Soldering	Peak temperature (molten solder temperature) : 260°C or below Time at peak temperature : 10 seconds or less Preheating temperature (package surface temperature) : 120°C or below Maximum number of flow processes : 1 time Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	WS260
Partial Heating	Peak temperature (pin temperature) : 350°C or below Soldering time (per side of device) : 3 seconds or less Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).

Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

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